

Vishay Semiconductors

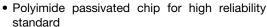
## Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> per leg	30 A			
$V_{R}$	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.20 V			
t <sub>rr</sub> typ.	37 ns			
T <sub>J</sub> max.	175 °C			
Package	TO-3PF			
Circuit configuration	Common cathode			

#### **FEATURES**

- Gen 4 FRED Pt technology
- Low I<sub>RBM</sub> and reverse recovery charge
- Very low forward voltage drop





- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

Gen 4 Fred Pt technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage	$V_{RRM}$		600	V	
Average rectified forward current, per leg	I <sub>F(AV)</sub>	T <sub>C</sub> = 75 °C	30	А	
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave	255		
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL TEST CONDITIONS MIN.		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 100 μA	600	-	-	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.4	1.65	V
		I <sub>F</sub> = 50 A	-	1.56	1.97	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.20	1.45	
		I <sub>F</sub> = 50 A, T <sub>J</sub> = 150 °C	-	1.43	-	1
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated -		-	50	
		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA
Junction capacitance	C <sub>T</sub>	C <sub>T</sub> V <sub>R</sub> = 600 V - 19		-	pF	



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/d$	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		36	-	
Reverse recovery time, per leg	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	70	-	ns
		T <sub>J</sub> = 125 °C		-	100	-	
Peak recovery current, per leg	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	17	-	Α
		T <sub>J</sub> = 125 °C		-	30	-	
Reverse recovery charge, per leg	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	800	-	nC
		T <sub>J</sub> = 125 °C		-	1800	-	i iic

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	2.4	°C/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>		-	0.4	-	
Mainh			-	6.2	-	g
Weight			-	0.21	-	oz.
Mounting torque			4.0 (3.5)	-	6.0 (5.3)	kgf · cm (lbf · in)
Marking device		Case style TO-3PF	C4ZU6006FP			

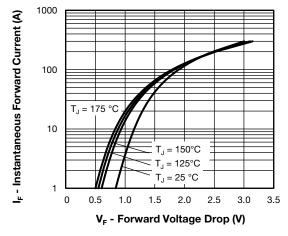


Fig. 1 - Typical Forward Voltage Drop Characteristics

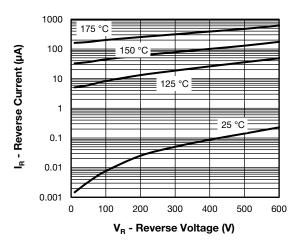


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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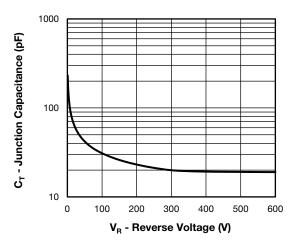


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

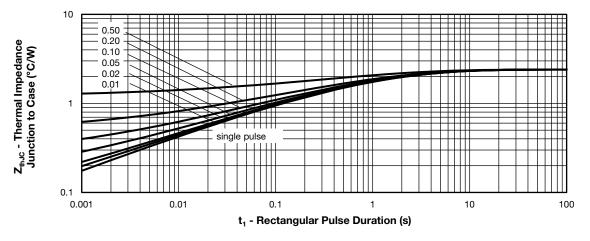


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

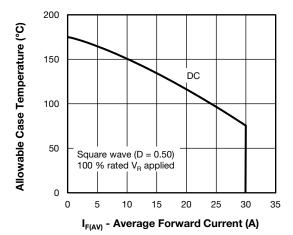


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

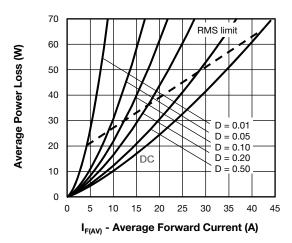
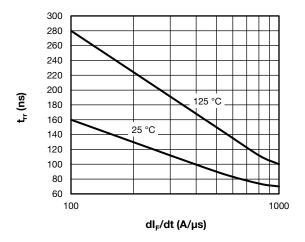


Fig. 6 - Forward Power Loss Characteristics



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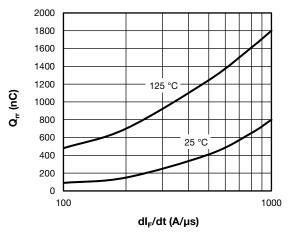
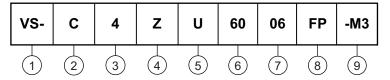


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

C = common cathode

FRED Pt Gen 4

4 - Z = TO-3PF package

5 - Process type:

U = ultrafast recovery

6 - Current rating (60 = 2 x 30 A)

7 - Voltage rating (06 = 600 V)

8 - FULL-PAK

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-C4ZU6006FP-M3	25	300	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions TO-3PF <u>www.vishay.com/doc?96691</u>				
Part marking information	TO-3PF	www.vishay.com/doc?96690		



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